

## Antimatter annihilation detection with AEGIS using silicon detectors

AEGIS  
(Antimatter  
Experiment:  
Gravity,  
Interferometry,  
Spectroscopy)  
is  
an  
antimatter  
experiment  
based  
at  
CERN,  
whose  
primary  
goal  
is  
to  
carry  
out  
the  
first  
direct  
measurement  
of  
the  
Earth's  
gravitational  
acceleration  
on  
antimatter.  
AEGIS  
will  
attempt  
to  
measure  
the  
gravitational  
acceleration  
for  
antihydrogen  
with  
1%  
relative  
precision,  
which  
would  
be  
the  
first  
precision

test  
of  
the  
Weak  
Equivalence  
Principle  
for  
antimatter.  
The  
principle  
of  
the  
experiment  
is  
based  
on  
the  
formation  
of  
antihydrogen  
through  
a  
charge  
exchange  
reaction  
between  
laser  
excited  
(Rydberg)  
positronium  
and  
cold  
(100  
mK)  
antiprotons.  
The  
antihydrogen  
atoms  
will  
be  
accelerated  
by  
an  
inhomogeneous  
electric  
field  
(Stark  
acceleration)  
to  
form  
a  
pulsed  
cold  
beam.  
The  
free  
fall  
of  
the

antihydrogen  
due  
to  
Earth's  
gravity  
will  
be  
measured  
using  
a  
moiré  
deflectometer  
and  
a  
hybrid  
position  
detector.  
This  
detector  
will  
consist  
of  
an  
active  
silicon  
part,  
where  
the  
annihilation  
of  
antihydrogen  
takes  
place,  
followed  
by  
an  
emulsion  
part  
coupled  
to  
a  
fiber  
time--  
of--flight  
detector.  
This  
overview  
presents  
the  
current  
results  
from  
the  
R&D  
efforts  
for  
the  
construction  
of

the  
silicon  
position  
detector.  
Low  
energy  
antiproton  
annihilations  
in  
silicon  
were  
studied  
in  
detail  
using  
different  
silicon  
sensor  
technologies.  
A  
first  
comparison  
between  
experimental  
data  
and  
Monte  
Carlo  
simulations  
for  
low  
energy  
antiproton  
annihilation  
is  
also  
reported,  
suggesting  
areas  
where  
the  
improvement  
of  
simulation  
models  
is  
possible.  
The  
outcome  
of  
these  
tests  
defined  
the  
basis  
for  
the  
final  
design

parameters  
of  
the  
silicon  
position  
detector.

This  
detector  
will  
consist  
of  
a  
50  
 $\mu\text{m}$   
thick  
silicon  
strip  
sensor

bonded to an application specific integrated circuit (ASIC) with self-triggering  
readout capabilities and a timing resolution in the order of  $\mu\text{s}$ .

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